Surface Mount

Monolithic Amplifier

DC-2 GHz

Product Features

- Wideband, DC to 2 GHz
- Cascadable
- Aqueous washable



VAM-6+

CASE STYLE: MMM168 PRICE: \$1.16 ea. QTY. (30)

+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

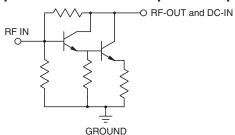
Typical Applications

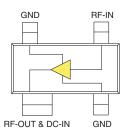
- Cellular
- PCN
- Instrumentation
- UHF/VHF

General Description

VAM-6+ (RoHS compliant) is wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in an SOT143 style package. It uses Darlington configuration and are fabricated using silicon technology. Expected MTBF is 1500 years at 85°C case temperature.

simplified schematic and pin description





Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.





Electrical Specifications at 25°C and 16mA, unless noted

Parameter		Min.	Тур.	Max.	Units
Frequency Range*		DC		2	GHz
Gain	f=0.1 GHz		19.5		dB
	f=1 GHz f=2 GHz	8.0	15.0 10.0		
	1-2 GHZ	0.0	10.0		
Input Return Loss	f=DC to 2 GHz		12.5		dB
Output Return Loss	f=DC to 2 GHz		14		dB
Output Power @ 1 dB compression	f=0.5 GHz		+2.0		dBm
Output IP3	f=0.5 GHz		+14		dBm
Noise Figure	f=0.5 GHz		3.0		dB
Recommended Device Operating Current			16		mA
Device Operating Voltage			3.3		V
Device Voltage Variation vs. Temperature at 16 mA			-5.6		mV/°C
Device Voltage Variation vs. Current at 25°C		8.4		mV/mA	
Thermal Resistance, junction-to-case ¹			505		°C/W

^{*}Guaranteed specification DC-2 GHz. Low frequency cut off determined by external coupling capacitors.

Absolute Maximum Ratings

Parameter	Ratings
Operating Temperature*	-20°C to 85°C
Storage Temperature	-55°C to 100°C
Operating Current	40mA
Power Dissipation	125mW
Input Power	13dBm

Note: Permanent damage may occur if any of these limits are exceeded.

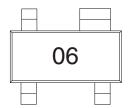




These ratings are not intended for continuous normal operation.

¹Case is defined as ground leads. *Based on typical case temperature rise 5°C above ambient.

Product Marking



Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: MMM168

VAM-6+: Plastic molded SOT143 style package, lead finish: tin/silver/nickel

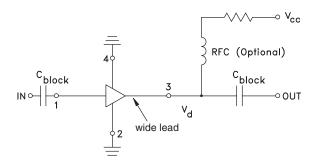
Tape & Reel: F8

Suggested Layout for PCB Design: PL-251

Evaluation Board: TB-415-6+

Environmental Ratings: ENV08

Recommended Application Circuit



R BIAS				
Vcc	"1%" Res. Values (ohms for Optimum Biasing			
6	154			
7	215			
8	280			
9	340			
10	402			
11	464			
12	536			
13	590			
14	665			





VAM-6+

ESD Rating

Human Body Model (HBM): Class 1C (1000 v to < 2000 v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (< 100 v) in accordance with ANSI/ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart

